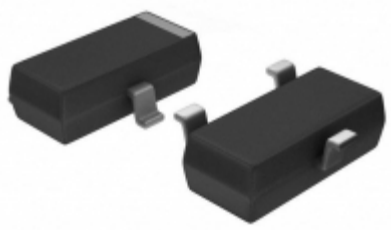





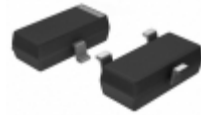


	<h2 style="color: red;">FJV3113RMTF</h2>
	<p>Hersteller-Teilenummer: FJV3113RMTF</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS NPN 200MW SOT23-3</p> <p>Datenblätter: 1.FJV3113RMTF.pdf 2.FJV3113RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 51980 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV3113RMTF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	51980 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	68 @ 5mA, 5V
Frequenz - Übergang	250MHz
Widerstand - Base (R1) (Ohm)	2.2k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Tape & Reel (TR)

FJV3113RMTF ist neu im Original, Suche FJV3113RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3113RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3113RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV3114RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3114RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3112RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3113RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>
 <p>FJV3111RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3111RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3112RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3115RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>

heiße Teile

Mehr

FJV3101RMTF	FJV3102RMTF	FJV3102RMTF	FJV3103RMTF	FJV3103RMTF
FJV3104RMTF	FJV3104RMTF	FJV3105RMTF	FJV3105RMTF	FJV3106RMTF
FJV3106RMTF	FJV3107RMTF	FJV3107RMTF	FJV3108RMTF	FJV3108RMTF
FJV3109R	FJV3109RMTF	FJV3109RMTF	FJV3110RMTF	FJV3110RMTF
FJV3111RMTF	FJV3111RMTF	FJV3112RMTF	FJV3112RMTF	FJV3113RMTF
FJV3114RMTF	FJV3114RMTF	FJV3115RMTF	FJV3115RMTF	FJV4101RMTF
FJV4101RMTF	FJV4102RLIMTF	FJV4102RMTF	FJV4102RMTF	FJV4103RMTF
FJV4103RMTF	FJV4104RMTF	FJV4104RMTF	FJV4105RMTF	FJV4105RMTF
FJV4106RMTF	FJV4106RMTF	FJV4107RMTF	FJV4107RMTF	FJV4108RMTF
FJV4108RMTF	FJV4109RMTF	FJV4109RMTF	FJV4110RMTF	FJV4110RMTF

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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